STTS2002

## 2.3 V memory module temperature sensor with a 2 Kb SPD EEPROM

Data brief

Features

- STTS2002 is a 2.3 V memory module temperature sensor with 2 Kb SPD EEPROM forward compatible with JEDEC standard TSE 2002a2 and backward compatible with STTS424E02

- Operating temperature range:
  - –40 °C to +125 °C

- Single supply voltage: 2.3 V to 3.6 V

- 2 mm x 3 mm TDFN8, height: 0.80 mm (max)[a]

- RoHS compliant, halogen-free

Temperature sensor

- Temperature sensor resolution: programmable (9-12 bits) 0.25 °C (typ)/LSB - (10-bit) default

- Temperature sensor accuracy (max):
  - ± 1 °C from +75 °C to +95 °C
  - ± 2 °C from +40 °C to +125 °C
  - ± 3 °C from –40 °C to +125 °C

- ADC conversion time: 125 ms (max) at default resolution (10-bit)

- Typical operating supply current: 160 µA (EEPROM standby)

- Temperature hysteresis selectable set points from: 0, 1.5, 3, 6.0 °C

- Supports SMBus timeout 25 ms - 35 ms

TDFN8 (DN)[a]
2 mm x 3 mm (max height 0.80 mm)
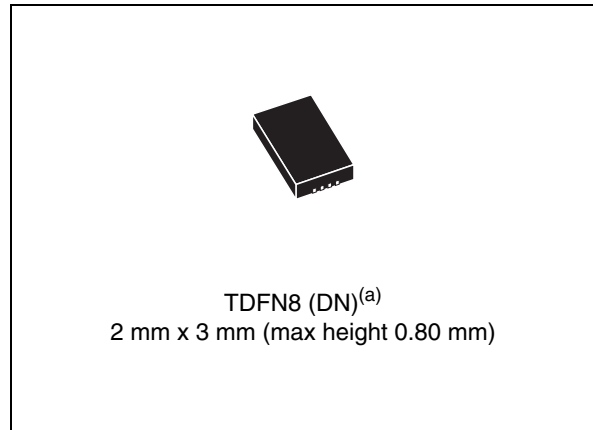
2 Kb SPD EEPROM

- Functionality identical to ST's M34E02 SPD EEPROM

- Permanent and reversible software data protection for the lower 128 bytes

- Byte and page write (up to 16 bytes)

- Self-time WRITE cycle (5 ms, max)

- Automatic address incrementing

Two-wire bus

- Two-wire SMBus/I^{2}C - compatible serial interface

- Supports up to 400 kHz transfer rate

- Does not initiate clock stretching

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a. Compliant to JEDEC MO-229, WCED-3

For further information contact your local STMicroelectronics sales office.

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1 Description

The STTS2002 is targeted for DIMM modules in mobile personal computing platforms (laptops), servers and other industrial applications. The thermal sensor (TS) in the STTS2002 is compliant with the JEDEC specification TSE2002a2, which defines memory module thermal sensors requirements for mobile platforms. The 2 Kbit serial presence detect (SPD) I^2C-compatible electrically erasable programmable memory (EEPROM) in the STTS2002 is organized as 256 x8 bits and is functionally identical to the industry standard M34E02.

The TS-SPD EEPROM combination provides space as well as cost savings for mobile and server platform dual inline memory modules (DIMM) manufacturers, as it is packaged in the compact 2 mm x 3 mm 8-lead TDFN package with a thinner maximum height of 0.80 mm. The DN package is compliant to JEDEC MO-229, variation WCED-3.

The digital temperature sensor has a programmable 9-12 bit analog-to-digital converter (ADC) which monitors and digitizes the temperature to a resolution of up to 0.0625 °C. The default resolution is 0.25 °C/LSB (10-bit). The typical accuracies over these temperature ranges are:

● ±2 °C over the full temperature measurement range of –40 °C to 125 °C

● ±1 °C in the +40 °C to +125 °C active temperature range, and

● ±0.5 °C in the +75 °C to +95 °C monitor temperature range

The temperature sensor in the STTS2002 is specified for operating at supply voltages from 2.3 V to 3.6 V. Operating at 3.3 V, the typical supply current is 160 µA (includes SMBus communication current).

The on-board sigma delta ADC converts the measured temperature to a digital value that is calibrated in °C. For Fahrenheit applications, a lookup table or conversion routine is required. The STTS2002 is factory-calibrated and requires no external components to measure temperature.

The digital temperature sensor component has user-programmable registers that provide the capabilities for DIMM temperature-sensing applications. The open drain event output pin is active when the monitoring temperature exceeds a programmable limit, or it falls above or below an alarm window. The user has the option to set the event output as a critical temperature output. This pin can be configured to operate in either a comparator mode for thermostat operation or in interrupt mode.

The 2 Kbit serial EEPROM memory in the STTS2002 has the ability to permanently lock the data in its first half (upper) 128 bytes (locations 00h to 7Fh). This feature has been designed specifically for use in DRAM DIMMs with SPD. All of the information concerning the DRAM module configuration (e.g. access speed, size, and organization) can be kept write protected in the first half of the memory. The second half (lower) 128 bytes of the memory can be write protected using two different software write protection mechanisms.

By sending the device a specific sequence, the first 128 bytes of the memory become write protected: permanently or resettable. In the STTS2002 the write protection of the memory array is dependent on whether the software protection has been set.

Figure 1.   Logic diagram
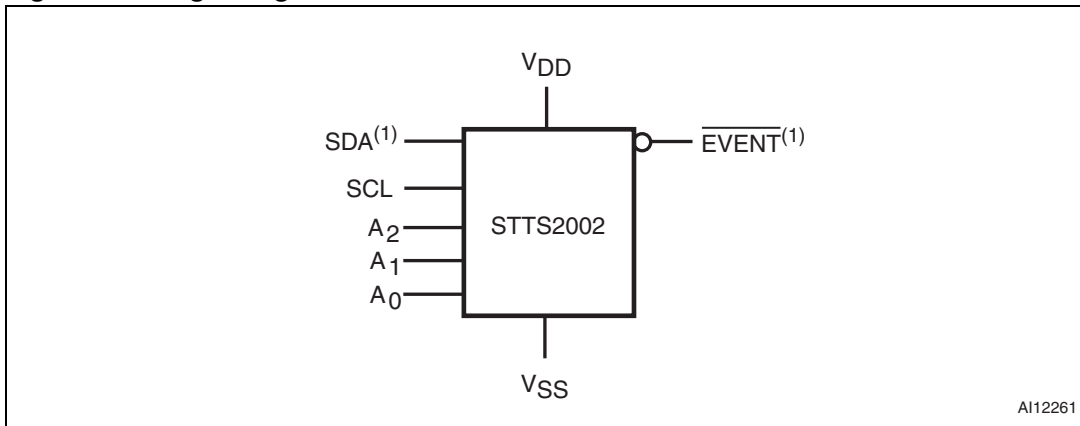
1. SDA and $\overline{\text{EVENT}}$ are open drain.

Table 1.   Signal names

Pin	Symbol	Description	Direction
1	A0	Serial bus address selection pin. Can be tied to V_{SS} or V_{DD}.	Input
2	A1	Serial bus address selection pin. Can be tied to V_{SS} or V_{DD}.	Input
3	A2	Serial bus address selection pin. Can be tied to V_{SS} or V_{DD}.	Input
4	V_{SS}	Supply ground	
5	SDA[1]	Serial data	Input/output
6	SCL	Serial clock	Input
7	$\overline{\text{EVENT}}$[1]	Event output pin. Open drain and active-low.	Output
8	V_{DD}	Supply power (2.3 V to 3.6 V)	

1. SDA and $\overline{\text{EVENT}}$ are open drain.

Figure 2.   TDFN8 connections (top view)
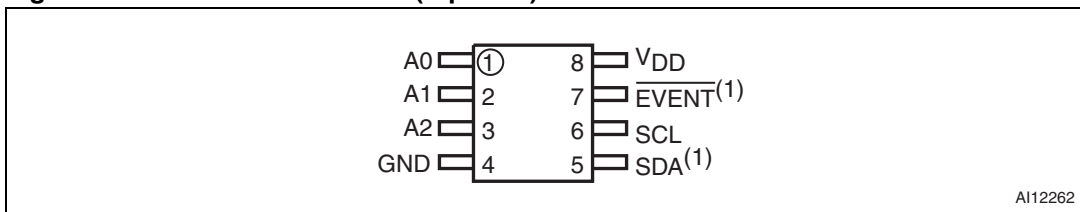
1. SDA and $\overline{\text{EVENT}}$ are open drain.

Figure 3. Block diagram

AI12278a
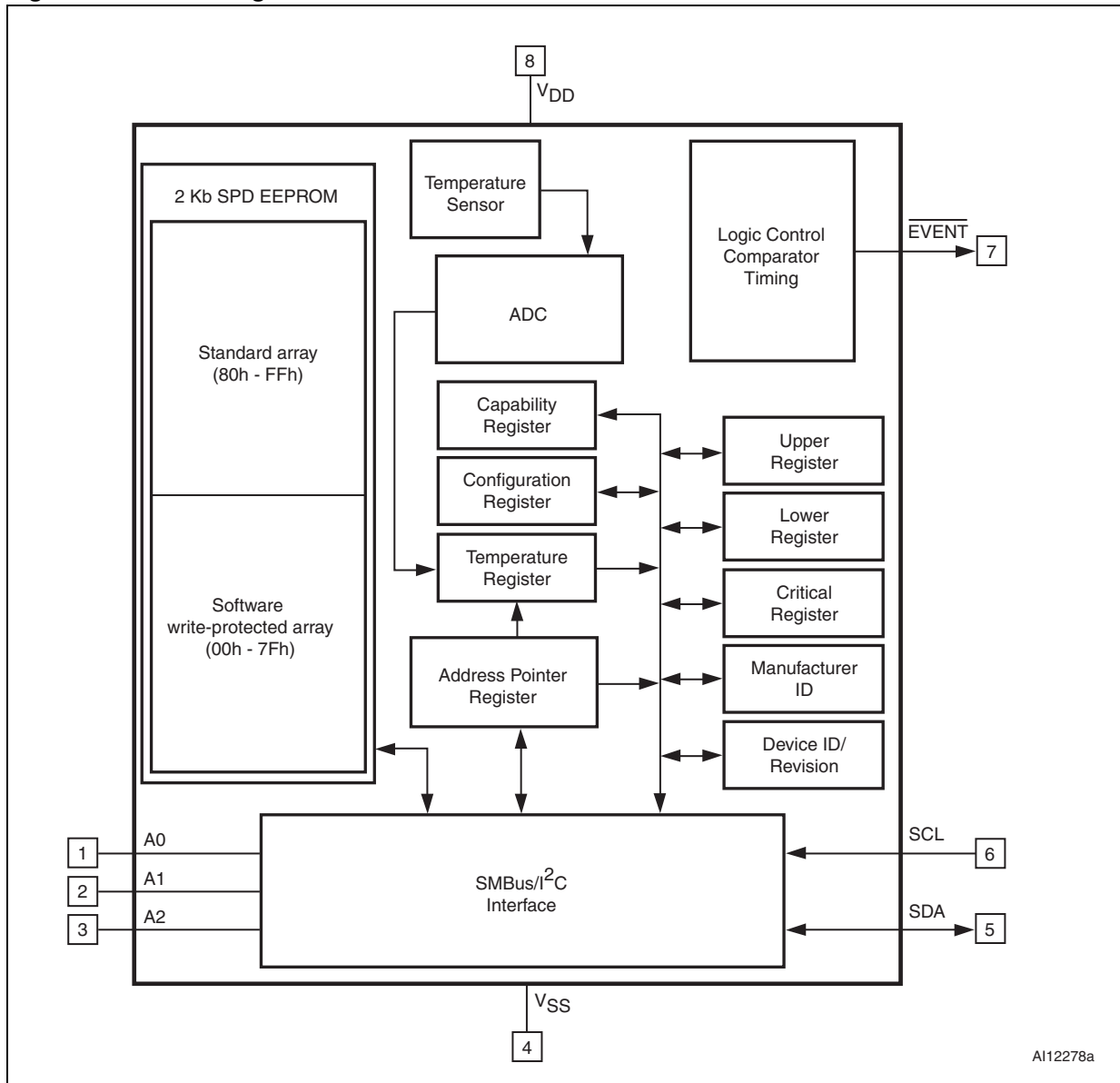
2 Temperature sensor registers

The temperature sensor component is comprised of various user-programmable registers. These registers are required to write their corresponding addresses to the pointer register. They can be accessed by writing to their respective addresses (see *Table 2*). Pointer register bits 7 - 4 must always be written to '0'. This must be maintained, as not setting these bits to '0' may keep the device from performing to specifications.

The main registers include the :
● Capability register (read-only)
● Configuration register (read/write)
● Temperature register (read-only)
● Temperature trip point registers (read/write), including
 – Alarm temperature upper boundary
 – Alarm temperature lower boundary and
 – Critical temperature
● Manufacturer's ID register (read-only)
● Device ID and device revision ID register (read-only)
● Temperature resolution register (TRES) (read/write)

Table 2. Temperature sensor registers summary

Address (hex)	Register name		Power-on default
Not applicable	Address pointer		Undefined
00	Capability	B-grade	0x006F
01	Configuration		0x0000
02	Alarm temperature upper boundary trip		0x0000
03	Alarm temperature lower boundary trip		0x0000
04	Critical temperature trip		0x0000
05	Temperature		Undefined
06	Manufacturer's ID		0x104A
07	Device ID/revision		0x0300
08	Temperature resolution register		0x0001

3 Part numbering

Table 3. Ordering information scheme

Example: STTS2002 B 2 DN 3 F

Device type

STTS2002

Accuracy grade

B: Maximum accuracy 75 °C to 95 °C = ± 1 °C

Voltage (minimum)

2 = 2.3 V - 3.6 V part

Package

DN = TDFN8 (0.80 mm max height)

Temperature

3 = –40 °C to 125 °C

Shipping method

F = ECOPACK® package, tape & reel packing

E = ECOPACK® package, tube packing

For other options, or for more information on any aspect of this device, please contact the ST sales office nearest you.

4 Package marking information

Figure 4. DN package topside marking information (TDFN8)

B2DN(1)
TSE2(2)
PYWW(3)

ai13907b
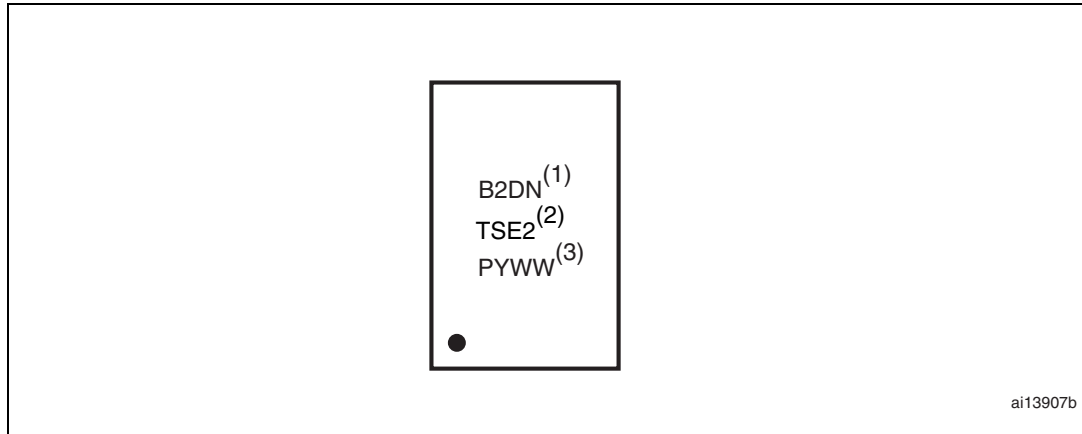
1. Temperature grade and package
   B = B-grade, stacked
   2 = Minimum operating voltage of 2.3 V
   DN = 0.80 mm TDFN package

2. Device name
   TSE2 = STTS2002

3. Traceability codes
   P = 2nd digit of plant code
   Y = Year
   WW = Work Week

5 Revision history

Table 4. Document revision history

Date	Revision	Changes
03-Mar-2010	1	Initial release.

Please Read Carefully: